



# Tremendously Increased Lifetime of MCP-PMTs

**Albert Lehmann,**

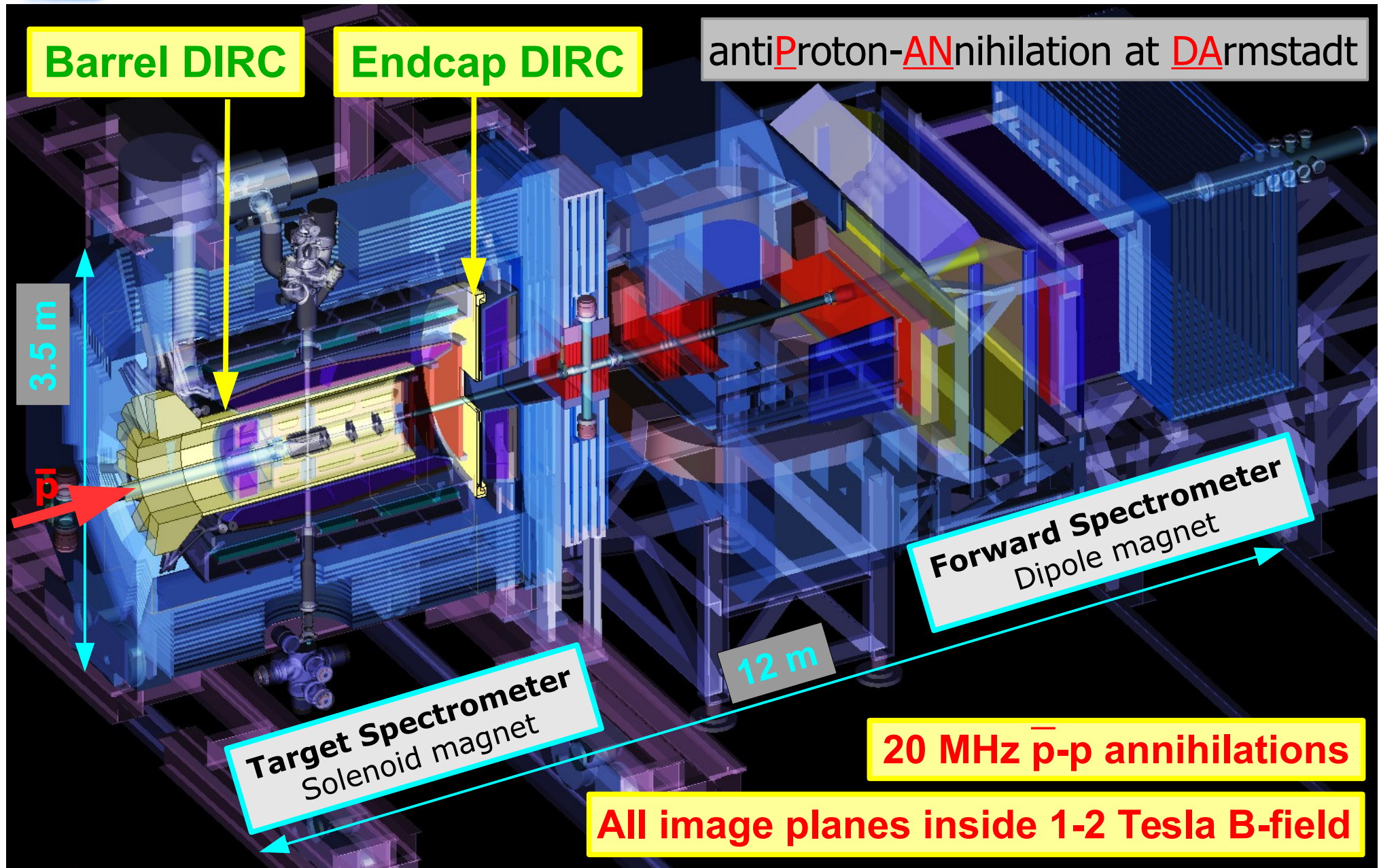
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for the PANDA Cherenkov Group

- Introduction and motivation
- Approaches to increase lifetime
- Results of aging tests
- Outlook and summary





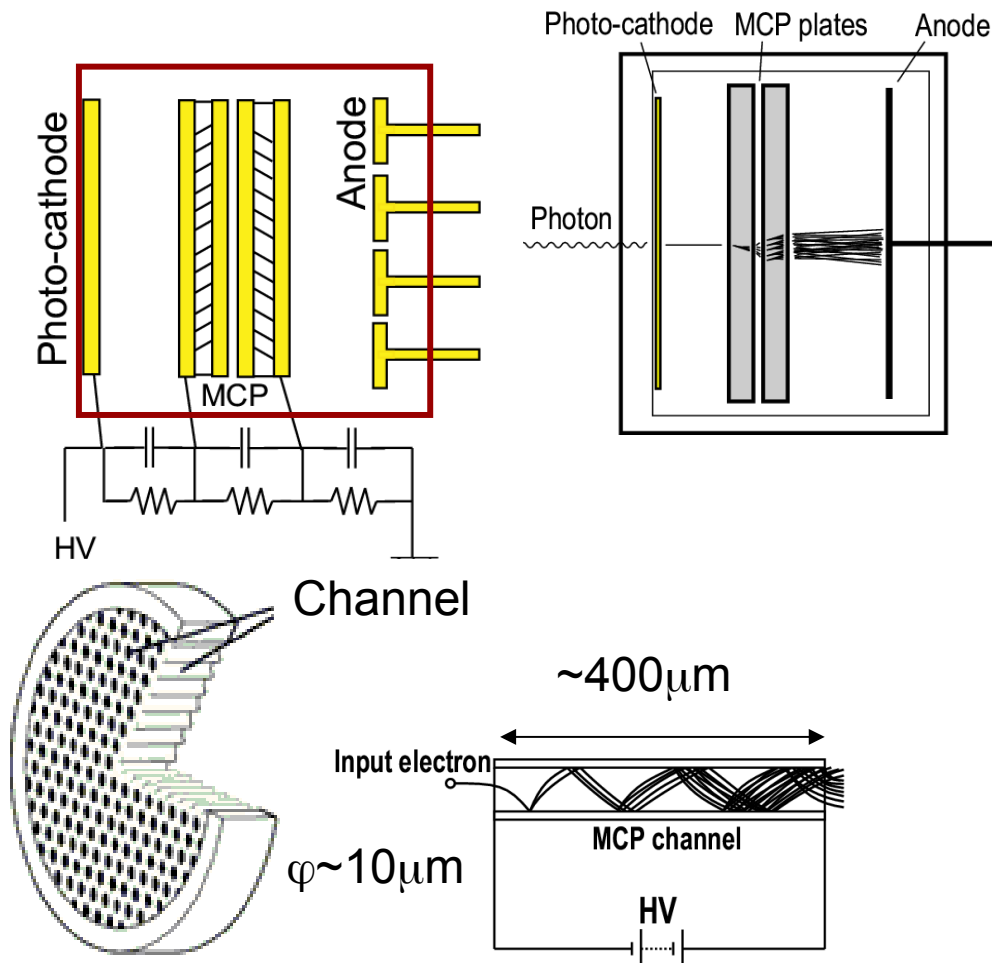
# PANDA Detector at FAIR





# Microchannel-Plate PMT

electron multiplication in glass capillaries ( $\varnothing \approx 10\text{-}25\ \mu\text{m}$ )



- usable in high magnetic fields
- high gain:
  - $>10^6$  with 2 MCP stages
  - single photon sensitivity
- very fast time response:
  - signal rise time = 0.3 – 1.0 ns
  - TTS < 50 ps
- low dark count rate
- quantum efficiency comparable to that of standard vacuum PMTs
- multi-anode PMTs available
- caveats:
  - lifetime (QE drops)
  - price



# Rate Estimates for PANDA

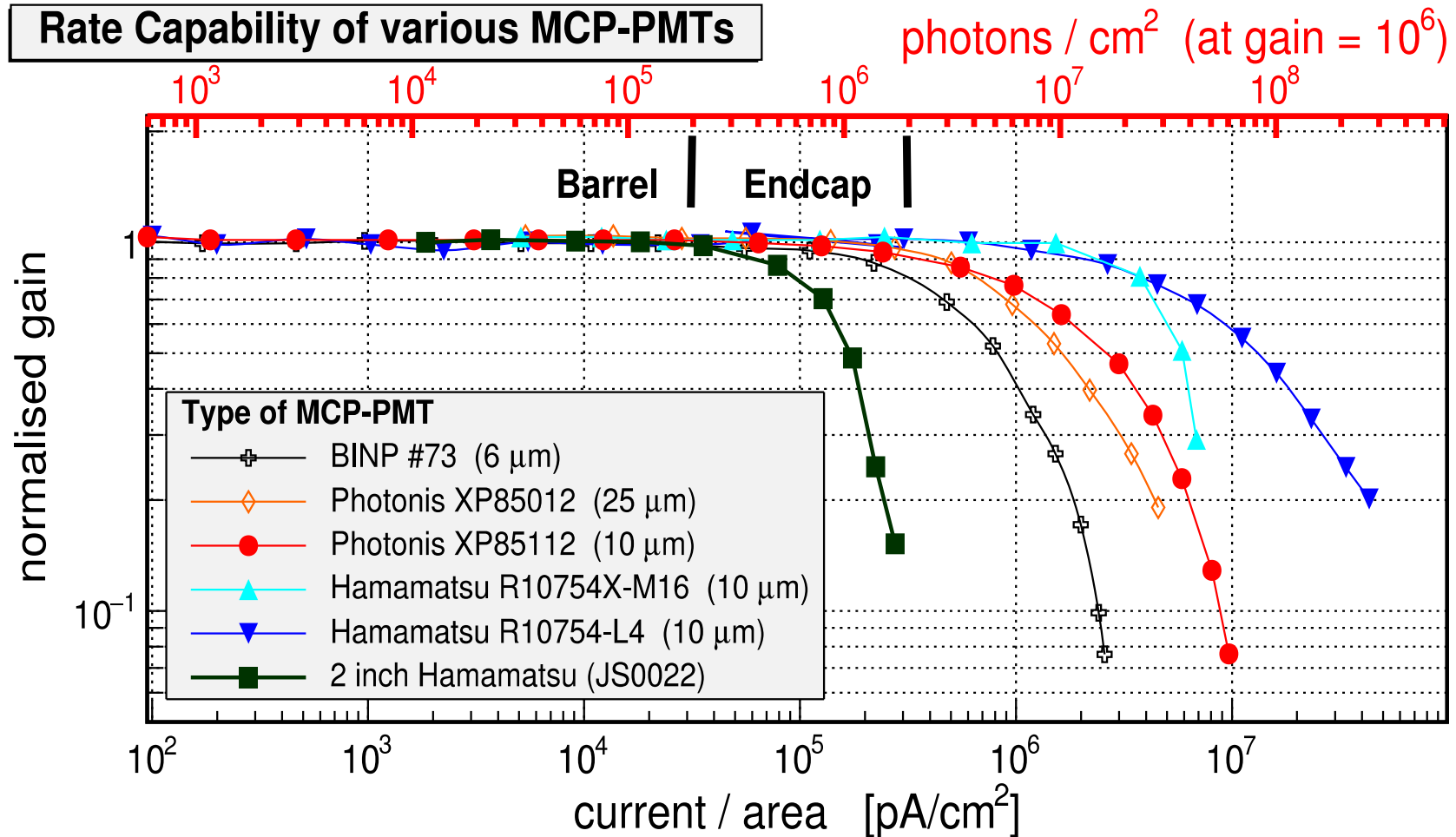
- **rate capability and lifetime are the most critical issues** for the application of MCP-PMTs in any high-rate experiment
- expected rates and anode charges of the PANDA DIRCs:

	total rate	anode rate (after Q.E.)	integrated anode charge / year	integrated anode charge / 10 years
	[MHz/cm <sup>2</sup> ]	[MHz/cm <sup>2</sup> ]	[C/cm <sup>2</sup> /year] at 10 <sup>6</sup> gain (at 100% dc)	[C/cm <sup>2</sup> ] at 10 <sup>6</sup> gain (at 50% duty cycle)
<b>Barrel DIRC</b>				
<i>at end of radiator</i>	60	5.6	28	
at readout plane	1.7	<b>0.2</b>	<b>1</b>	<b>5</b>
<b>Endcap DIRC</b>				
<i>at rim of radiator</i>	19	2	10	
focussing	7.5	<b>0.8</b>	<b>4</b>	<b>20</b>

- Endcap DIRC with much higher photon rate than Barrel DIRC  
→ **wavelength band filter to reduce photon rate to 5 C/cm<sup>2</sup>**



# Rate Capability



- most MCP-PMTs show **stable operation to ~200-300 kHz/cm<sup>2</sup> single photons** (at gain 10<sup>6</sup>)
- many recent MCP-PMT models stable up to >1 MHz/cm<sup>2</sup>

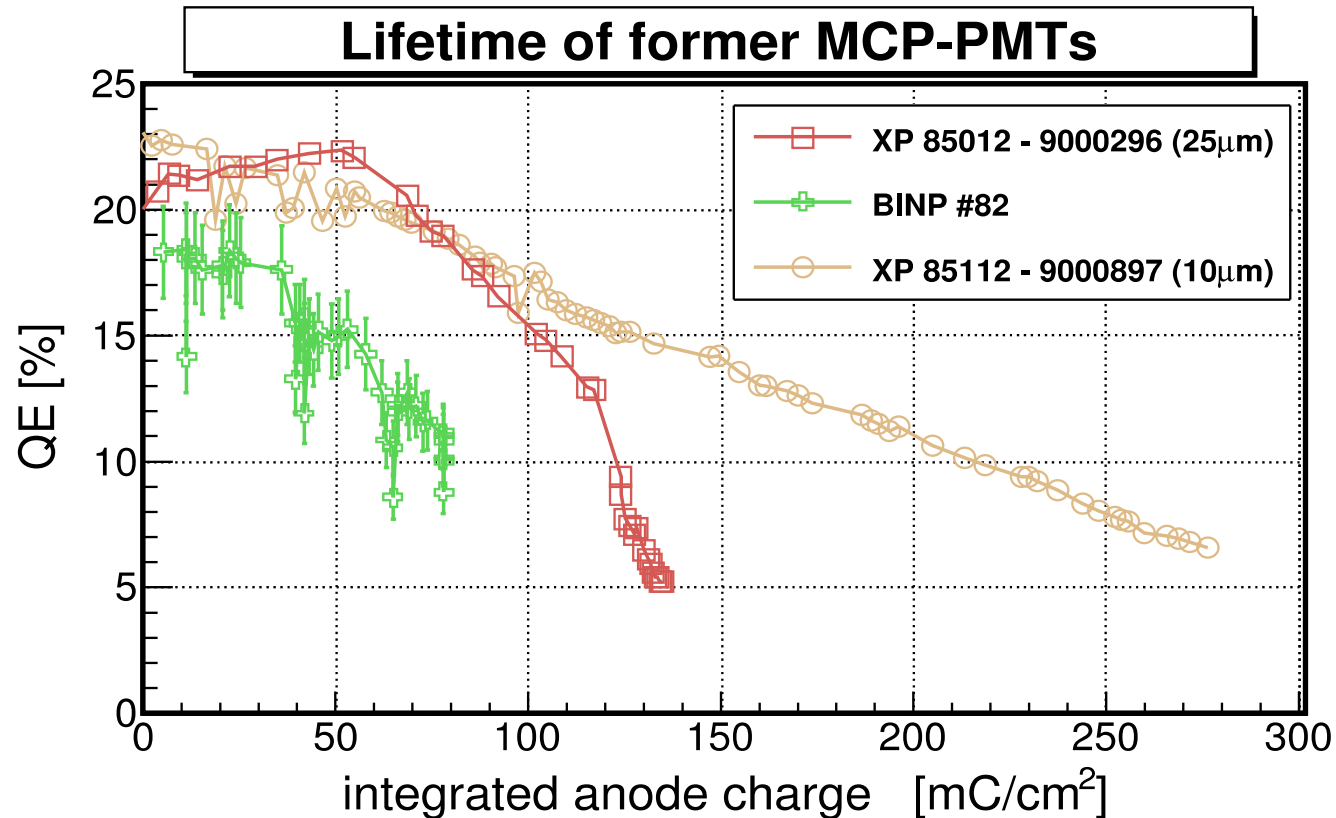




# Lifetime of former MCP-PMTs

**Status ~4 years ago**

- BINP with  $\text{Al}_2\text{O}_3$  film at MCP entrance to stop feedback ions
- PHOTONIS with improved vacuum and electron scrubbing of surfaces



- Quantum efficiency reduced by 50% or more at  $<200 \text{ mC/cm}^2$
- By far not sufficient for PANDA



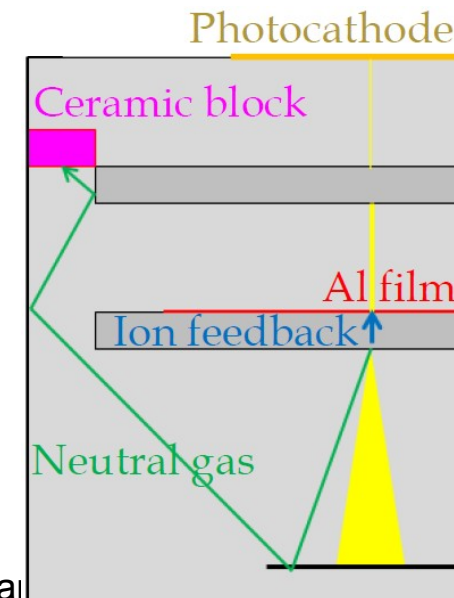
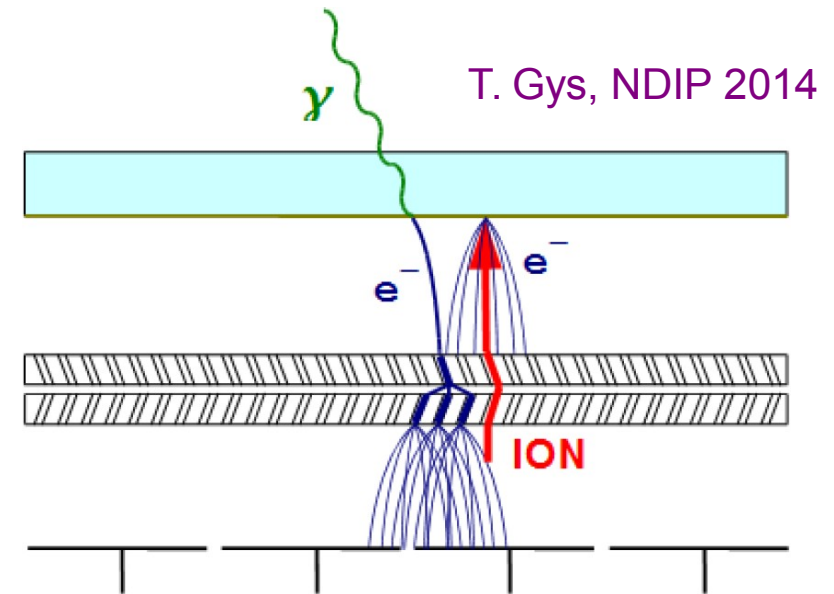
# Possible Cause of MCP Aging

## ● Ion feedback

- Amplification process causes
  - Desorption of atoms from MCP material (especially H and Pb)
  - Damage to MCP surfaces → gain may change
  - Ionization of residual gas atoms
- Ions accelerated towards photo cathode
  - Production of secondary pulse
  - Ions may react with PC
  - PC gets damaged and work function may gradually change
  - Degradation of Quantum efficiency (QE)

## ● Neutral molecules from residual gas

- Passing between MCPs and walls
- $\text{CO}_2$ ,  $\text{O}_2$  and  $\text{H}_2\text{O}$  react with PC

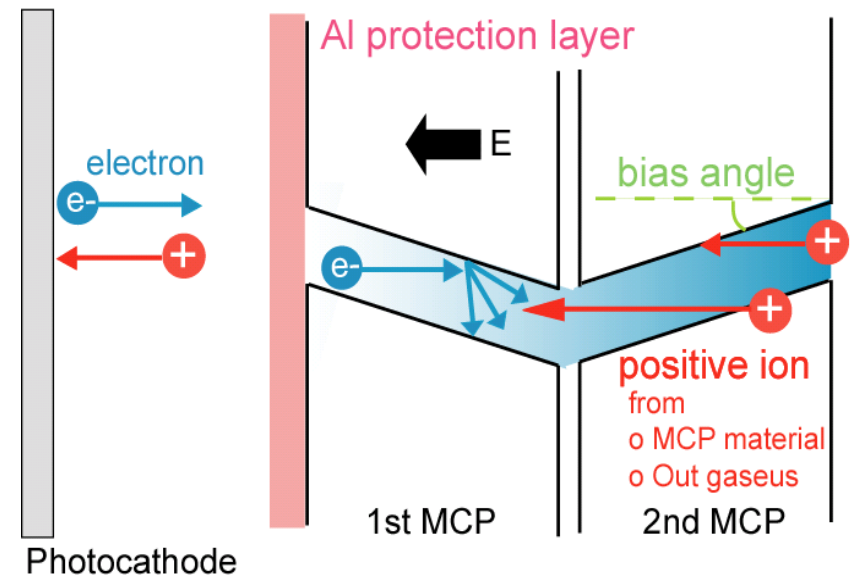


K. Matsuoka,  
RICH 2013

# First Approaches to Reduce Aging

## • Stop feedback ions by thin $\text{Al}_2\text{O}_3$ film (5-10 nm)

- In front of first MCP layer (older BINP and first Hamamatsu tubes)
  - disadvantage: another reduction of collection efficiency (CE) by about 1/3
- Later between MCP layers (second generation Hamamatsu tubes)
  - no CE reduction but higher HV needed



## • Improve vacuum quality

## • Improved cleaning of MCP surfaces

- Electron scrubbing (older PHOTONIS and latest BINP tubes)

## • Prevent neutral molecules in anode region from reaching the PC

- Anode region is hermetically sealed from PC region (2<sup>nd</sup> gen. Hamamatsu)
  - [NIM A629 (2011) 111]





# Production of more Robust PC

- MCP-PMTs developed at BINP for FARICH

- without protection layer
- with heavy electron scrubbing

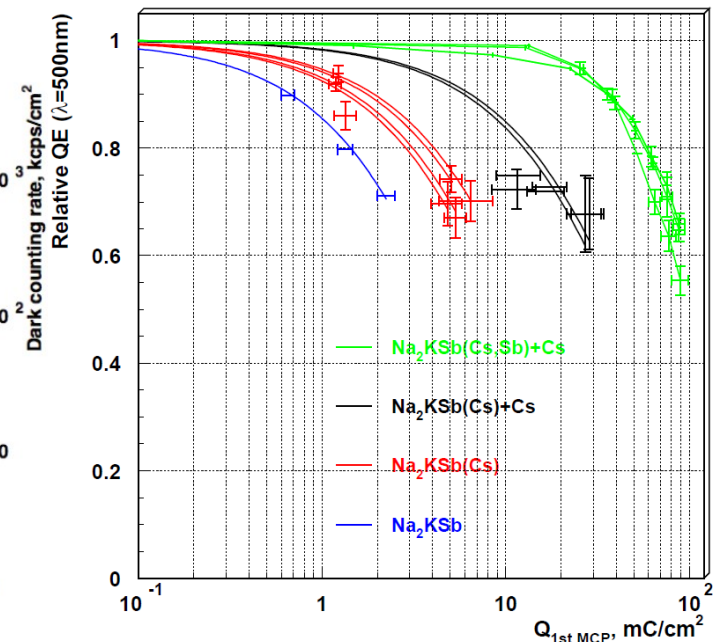
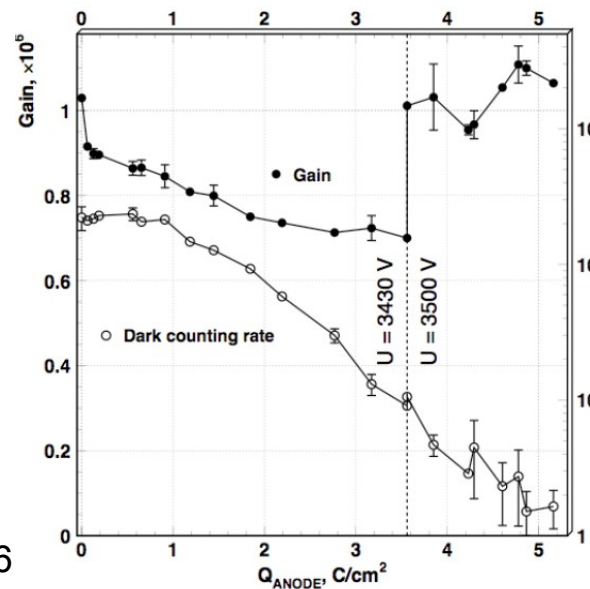
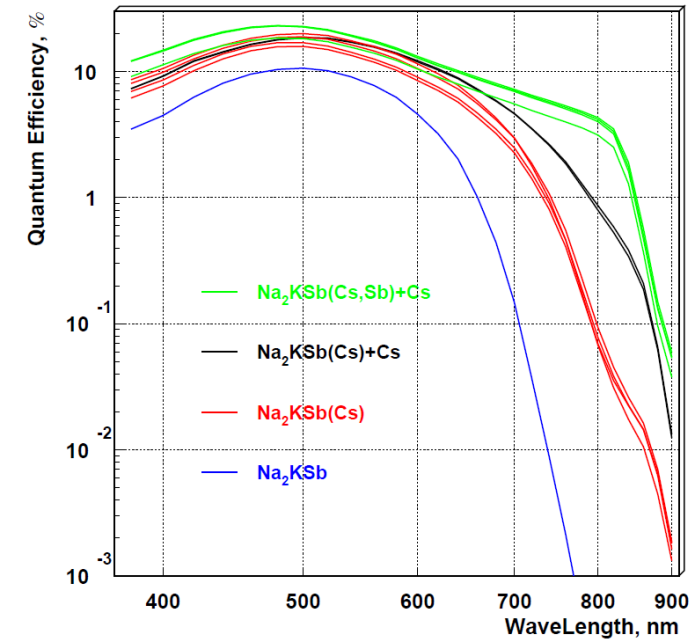
- New photo cathode [JINST 6 C12026 (2011)]

- $\text{Na}_2\text{KSb}$ : DCR < 0.5 kHz/cm<sup>2</sup>
- $\text{Na}_2\text{KSb}(\text{Cs})$ : DCR = 0.5 kHz/cm<sup>2</sup>
- $\text{Na}_2\text{KSb}(\text{Cs}) + \text{Cs}$ : DCR = 5 kHz/cm<sup>2</sup>
- $\text{Na}_2\text{KSb}(\text{Cs}) + \text{Cs}_3\text{Sb}$ : DCR = 50-100 kHz/cm<sup>2</sup>

- Gain recoverable

- Exponential reduction of dark count rate (DCR)

- Slower QE degradation





# Atomic Layer Deposition (ALD)

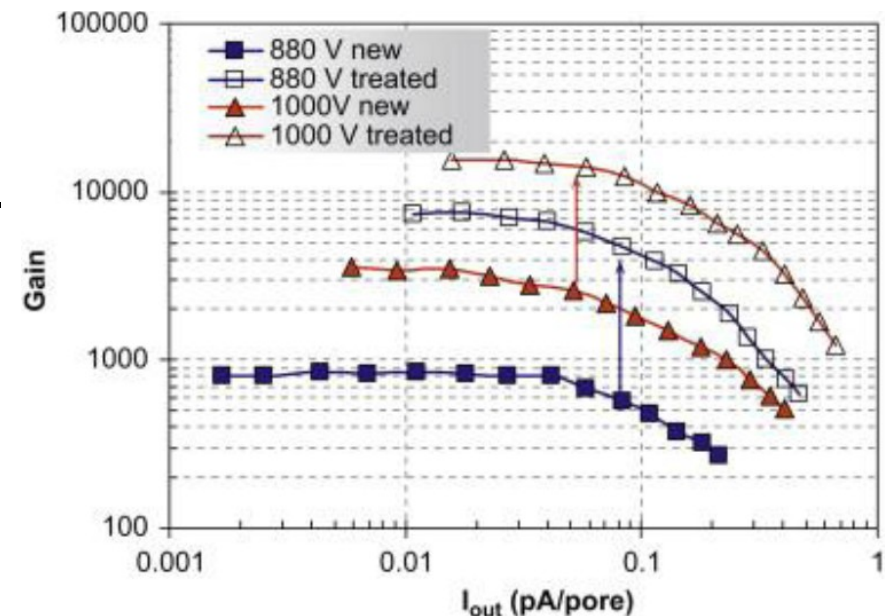
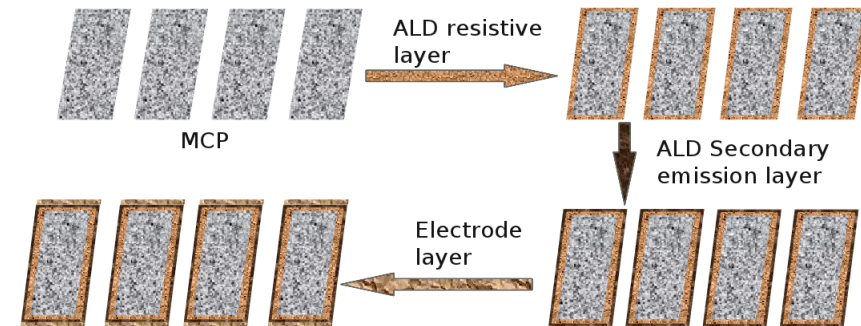
## Deposition of ultra-thin atomic layer (MgO, Al<sub>2</sub>O<sub>3</sub>) on MCP substrate

- MCP pores are coated in three steps
  - resistive layer
  - secondary electron emission (SEE) layer
  - electrode layer
- Optimization of MCP resistance and SEE
  - for each film independently
  - higher gain at given HV
- Arradance Inc. → PHOTONIS, LAPPD, ...

## Possibility to use MCP substrates other than lead glass

- e.g., borosilicate glass
  - higher bake-out temperature possible
  - fewer desorption during MCP operation

[NIM A639 (2011) 148]



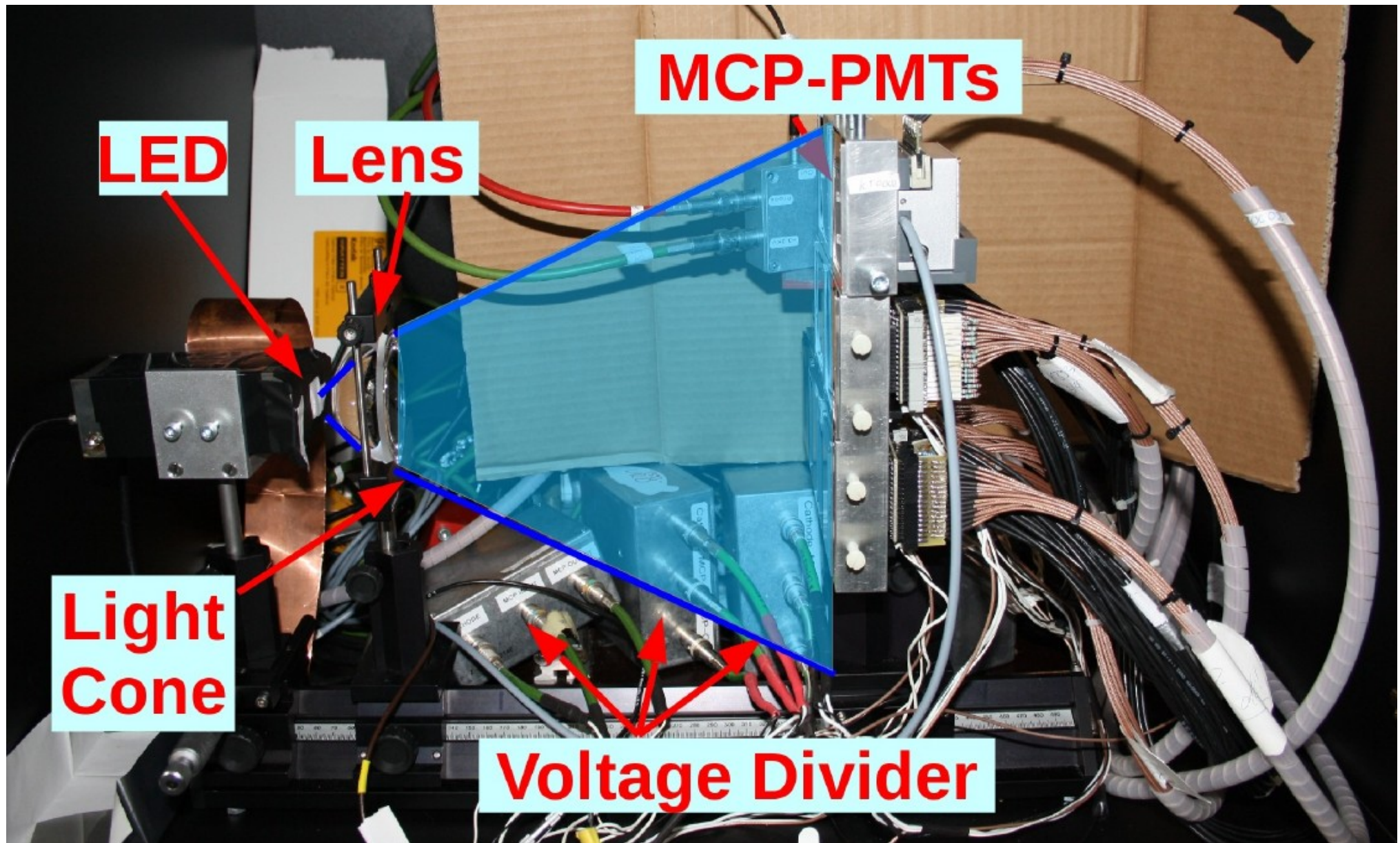
# Simultaneous Aging of MCP-PMTs

- **Problem in 2011:** The few aging tests existing were done in rather different environments → results are difficult to compare
- **Goal:** measure aging behavior for all available lifetime-enhanced MCP-PMTs in same environment
- **Simultaneous illumination** with common light source → same rate
- MCP-PMTs included in aging tests of last 4 years:
  - 2x BINP
    - improved vacuum and scrubbed surfaces + new photo cathode (both finished)
  - 4x Hamamatsu R10754X (1x1 inch<sup>2</sup>)
    - L4 and M16: protection layer (film) between 1<sup>st</sup> and 2<sup>nd</sup> MCP (both finished)
    - 2x M16M: ALD technique applied (+ film between MCPs) (started end 2013)
  - 3x PHOTONIS XP85112 (2x2 inch<sup>2</sup>)
    - 1-layer ALD surfaces (2x) and 2-layer ALD surfaces (1x, started Jan. 2014)
    - surface half covered during illumination (except 2-layer ALD tube)
  - 1x Hamamatsu R13266 (2x2 inch<sup>2</sup>) with ALD and film (started Dec. 2015)





# Illumination Setup







# Measurement of MCP Lifetime

## Continuous illumination

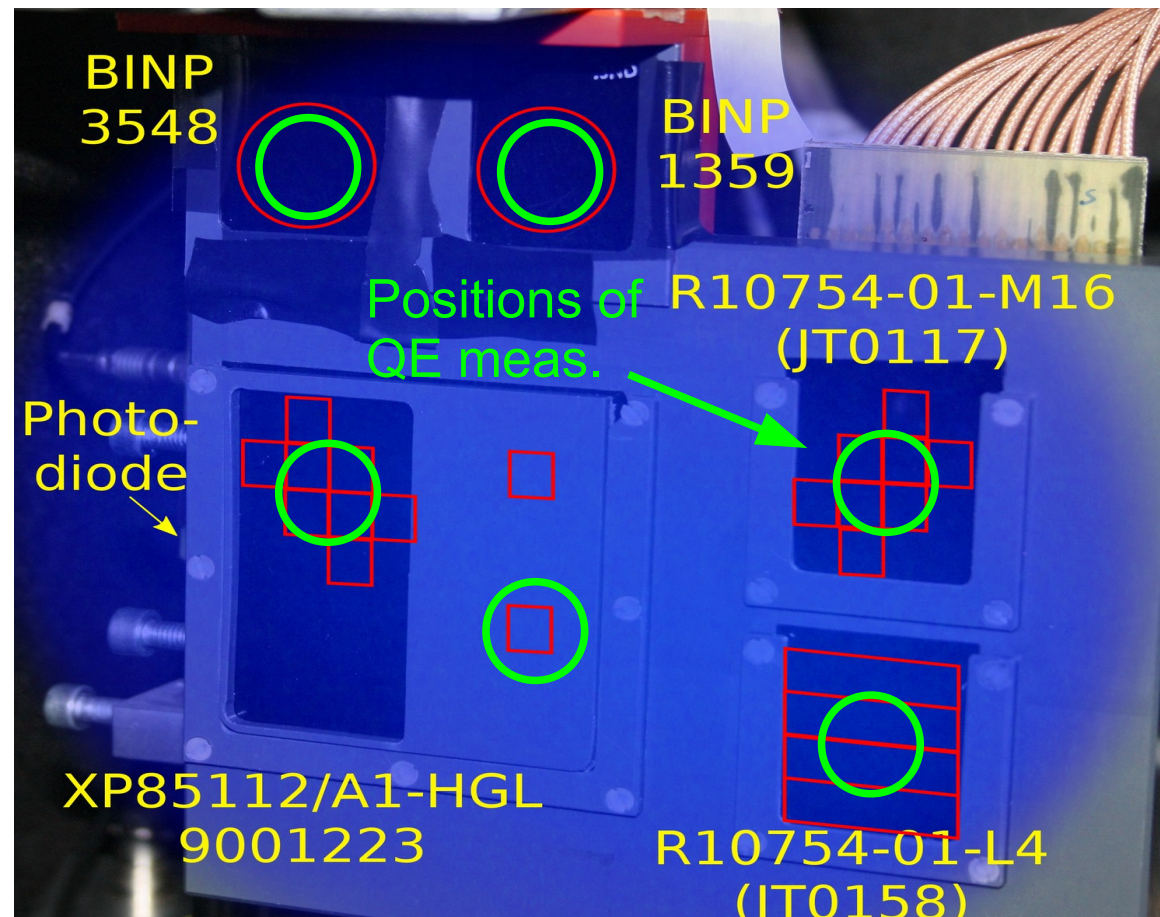
- 460 nm LED at 0.25 to 1 MHz rate attenuated to single photon level  
→ 3 to 20 mC/cm<sup>2</sup>/day

## Permanent monitoring

- MCP pulse heights and LED light intensity




## Q.E. measurements

- 250–700 nm wavelength band with monochromator  $\Delta\lambda = 1$  nm
- Every 2-3 weeks (at beginning days): wavelength scan
- Every 3-4 months (at beginning weeks): complete surface scan



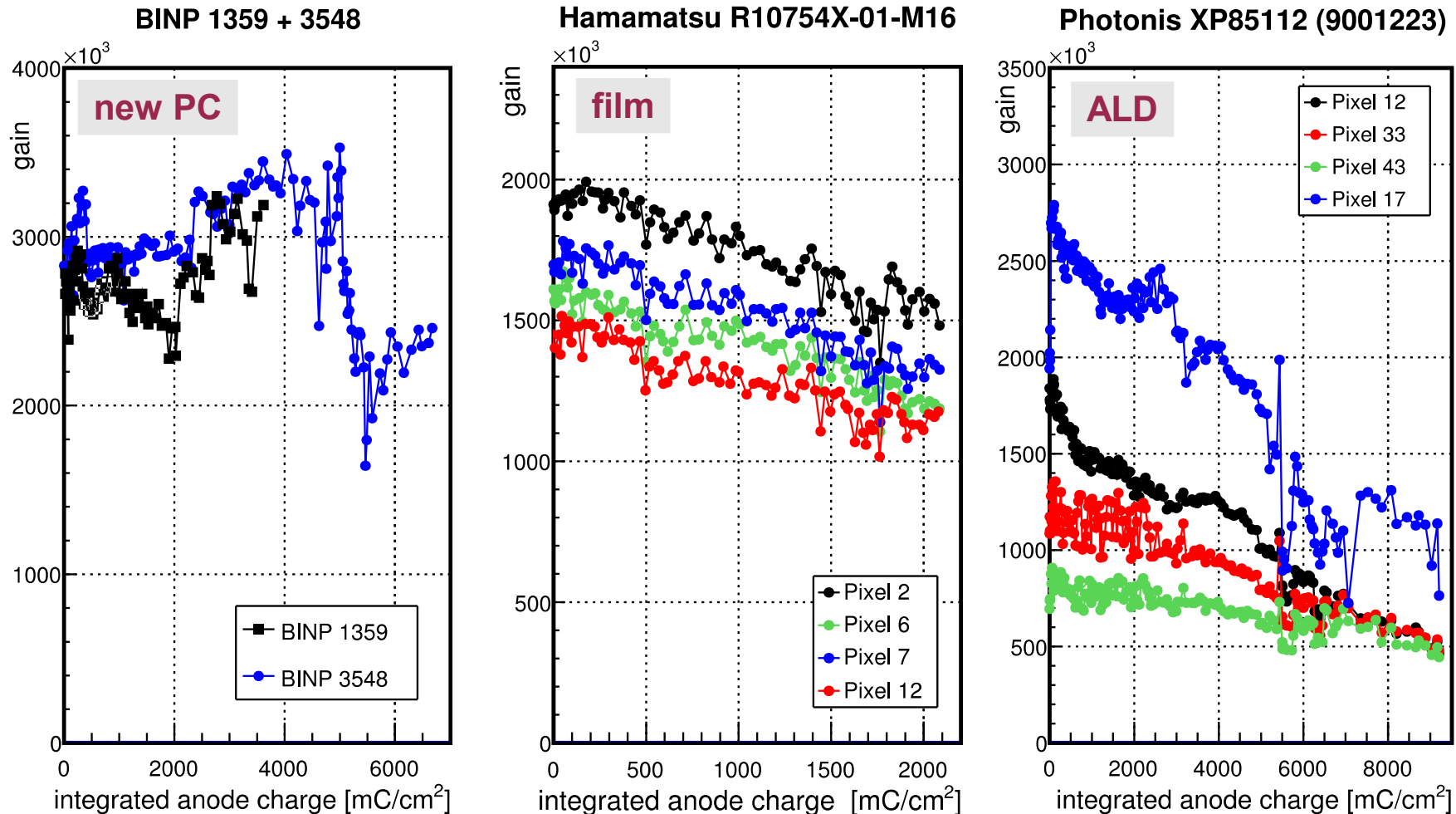


# Lifetime-Investigated MCP-PMTs

	BINP	PHOTONIS			Hamamatsu		
		XP85012	XP85112	XP85112	R10754X-01-M16	R10754X-07-M16M	R13266-07-M64
pore size (μm)	7	25	10	10	10	10	10
number of pixels	1	8x8	8x8	8x8	4x4	4x4	8x8
active area (mm²)	9² π	53x53	53x53	53x53	22x22	22x22	51x51
total area (mm²)	15.5² π	59x59	59x59	59x59	27.5x27.5	27.5x27.5	61x61
geom. efficiency (%)	36	81	81	81	61	61	70
photo cathode	Multi-alkali	bi-alkali			multi-alkali		
peak Q.E.	21% @ 495 nm	20% @ 380 nm	23% @ 380 nm	22% @ 380 nm	21% @ 375 nm	22% @ 415 nm	17% @ 415 nm
comments	better vacuum, new cathode	better vacuum, polished surfaces	better vacuum, polished surfaces	better vacuum, ALD surfaces	film between MCPs	ALD + film	ALD + film
# of tubes measured	2	1	1	3	1 (+1 L4)	2	1
							

- Tubes first measured with no significant lifetime improvements
- Lifetime improved tubes measurement started ~4 years ago
- Hamamatsu 1 inch ALD tubes measurement started ~2 year ago
- Hamamatsu 2 inch ALD tube just started

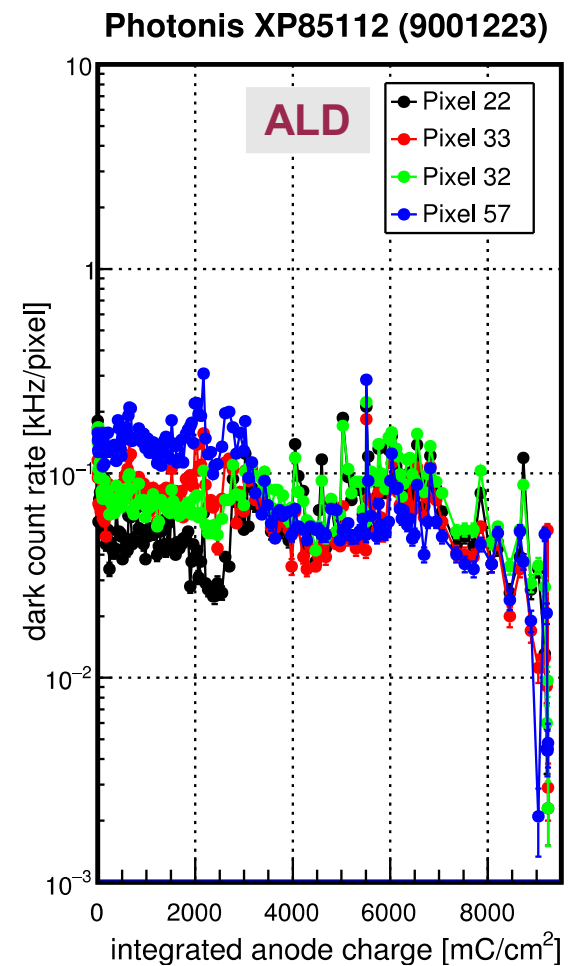
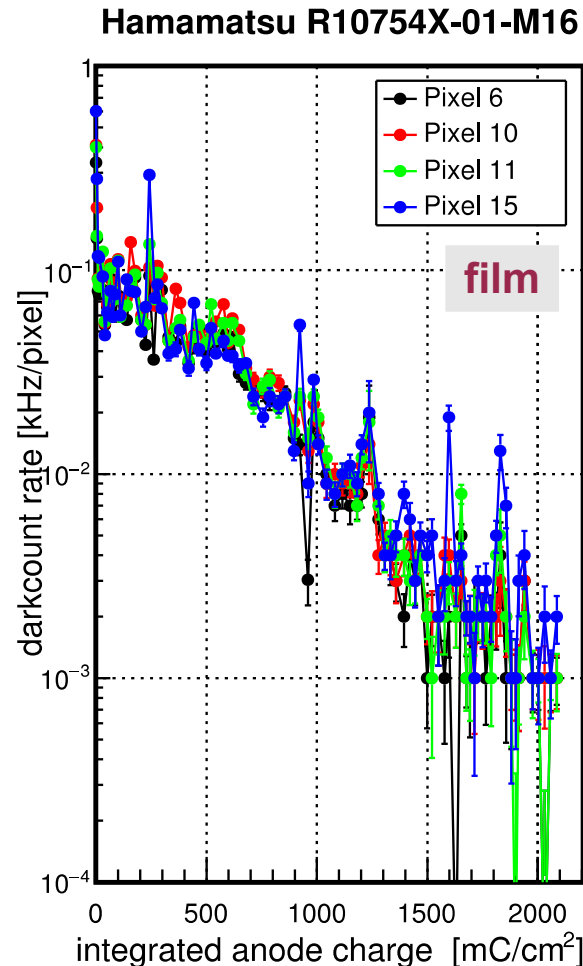
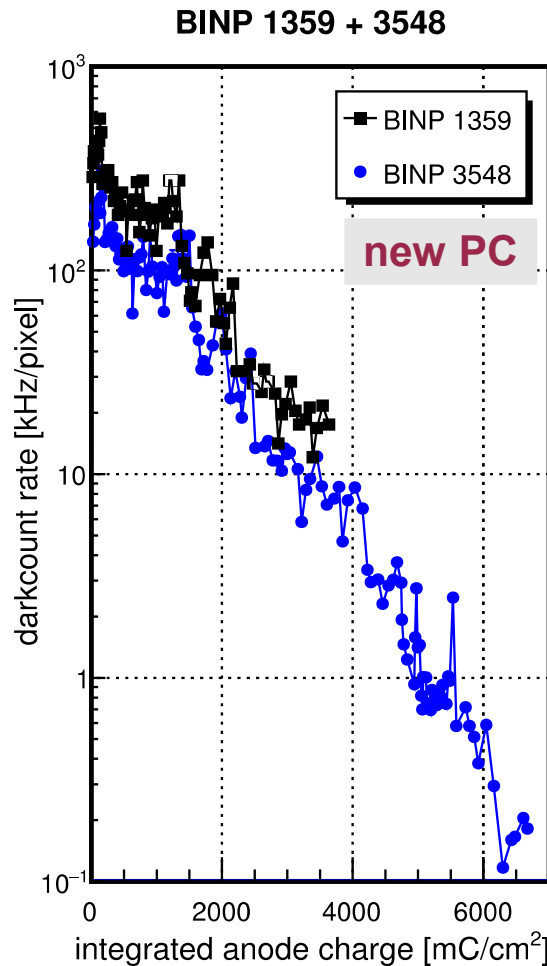
# Gain vs. Integrated Anode Charge



- Only moderate gain changes (except for PHOTONIS)
- This was quite different in the former MCP-PMTs !

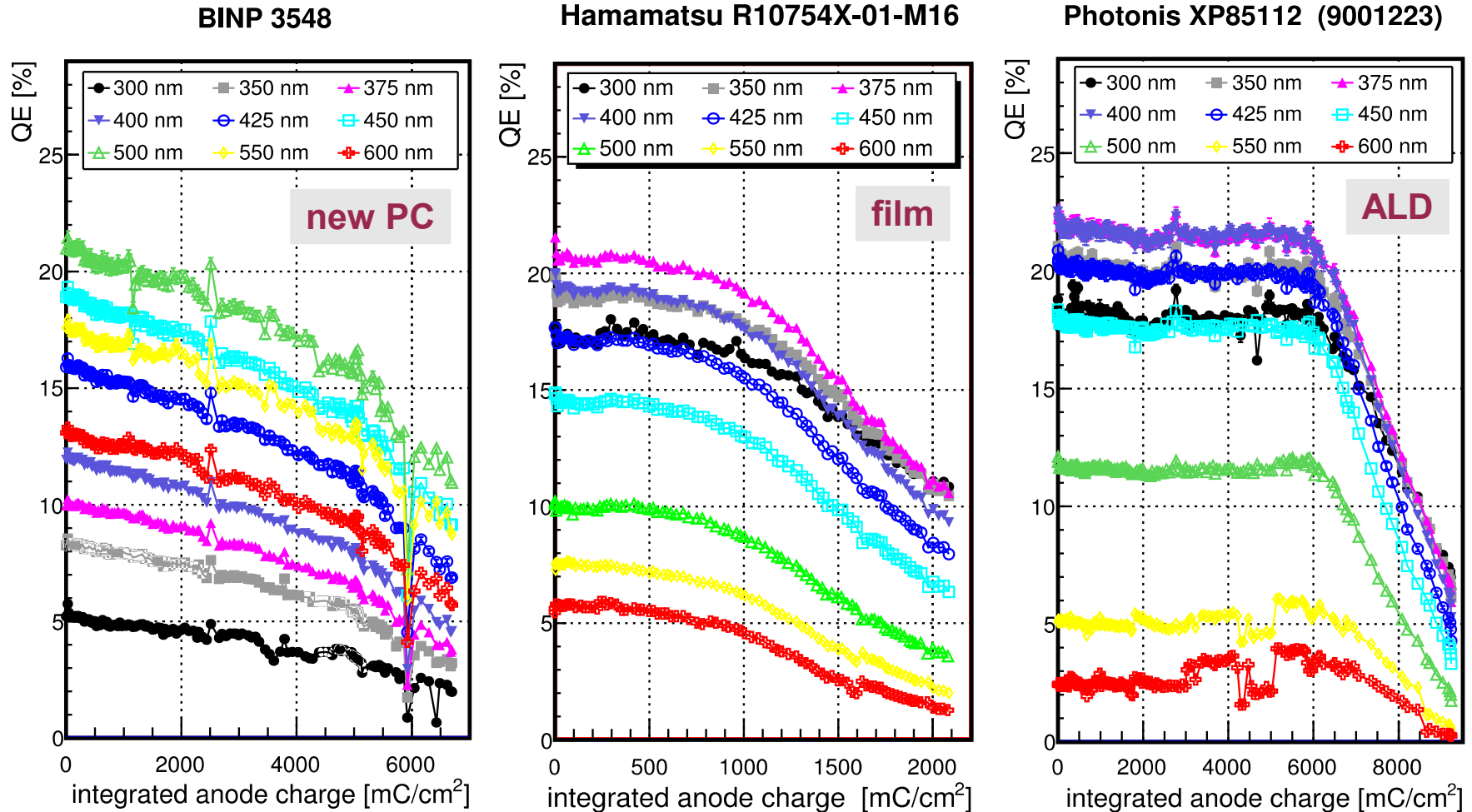


# Darkcount vs. Anode Charge



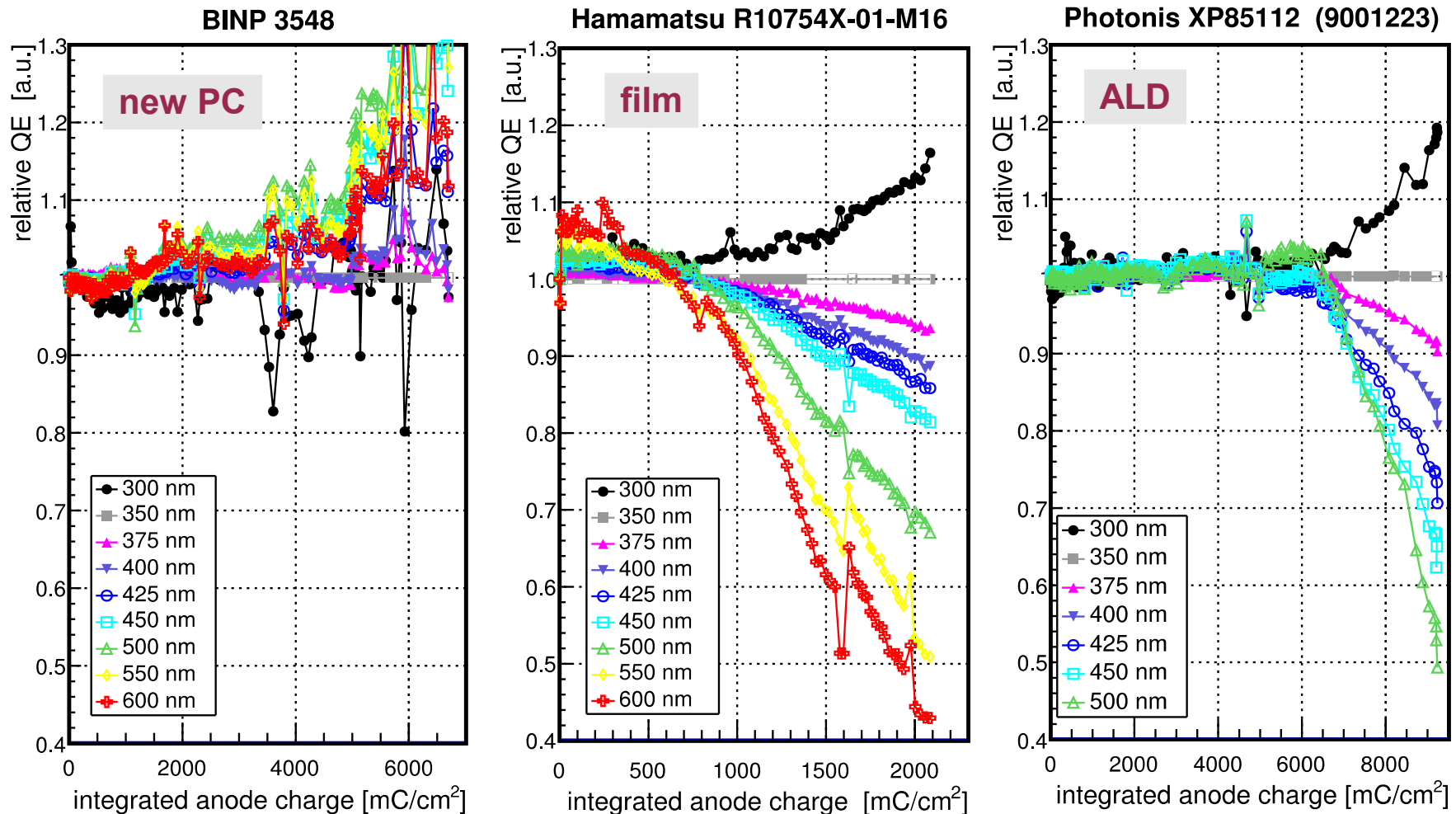
- Big exponential reduction in BINP and Hamamatsu R10754X
- Darkcount rate of PHOTONIS XP85112 (ALD) almost constant

# Q.E.( $\lambda$ ) vs. Integral Anode Charge



● BINP new PC:	continuous Q.E. degradation
● Hamamatsu film:	Q.E. drops significantly above ~1 C/cm²
● PHOTONIS ALD:	Q.E. degradation after 6 C/cm²

# Relative Q.E.( $\lambda$ ) vs. Anode Charge



● BINP new PC: signature not easy to interpret  
● Hamamatsu film and Photonis ALD: **once Q.E. starts degrading red light drops faster than blue (→ work function changes)**



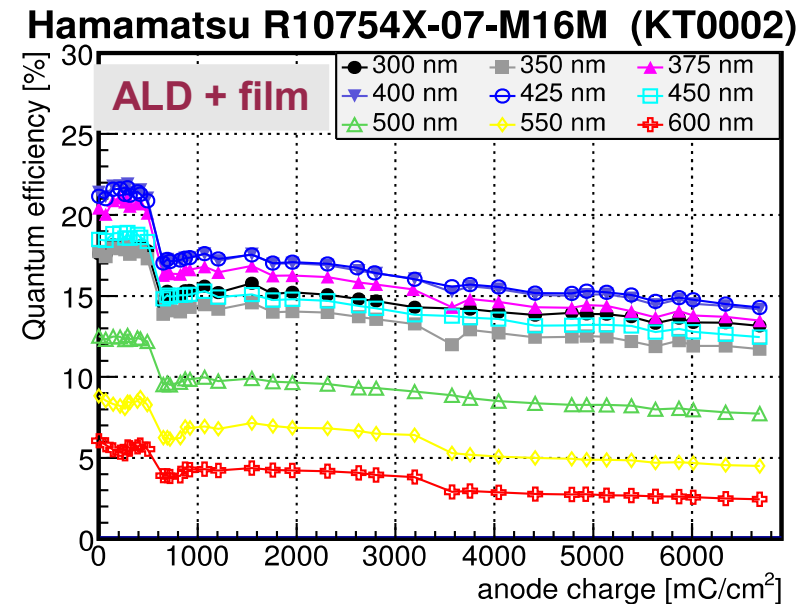
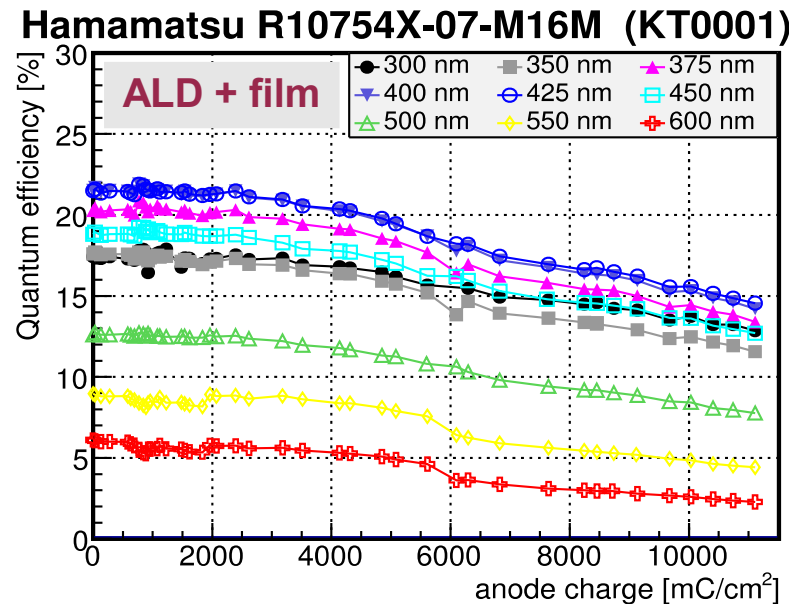
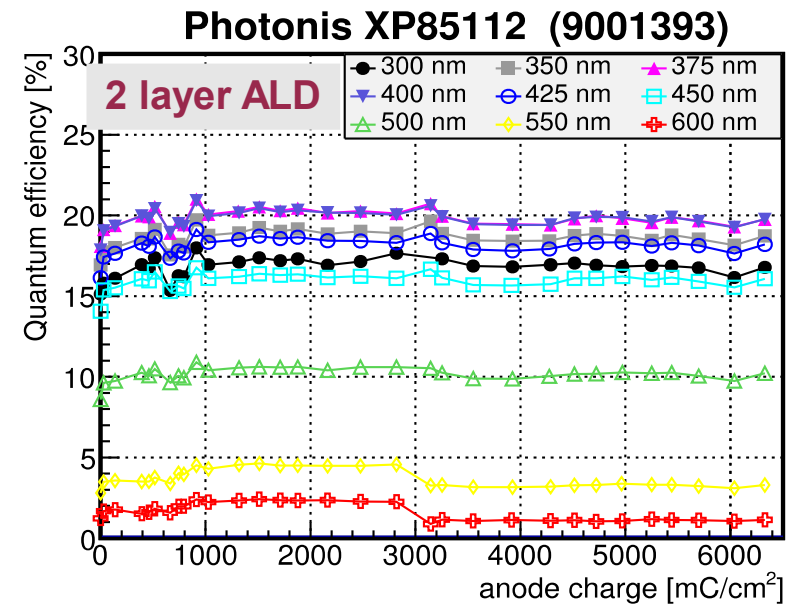
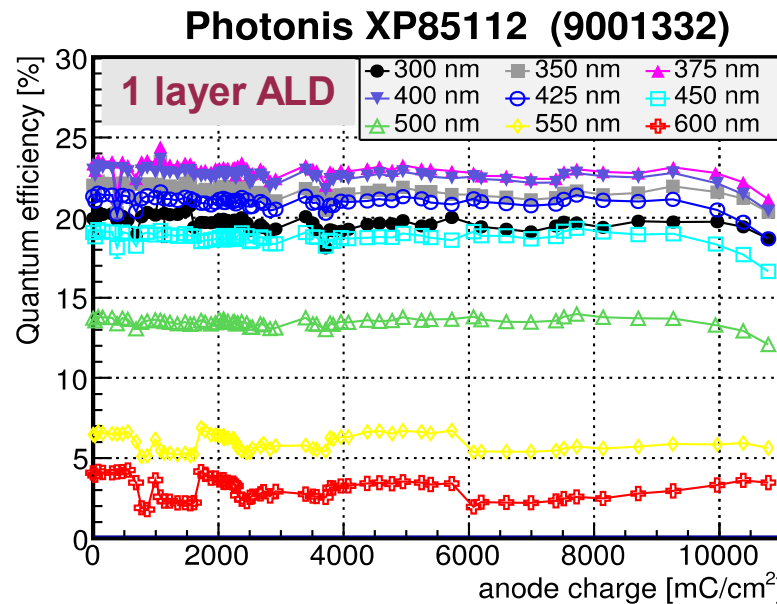


# Q.E.( $\lambda$ ) vs. Anode Charge

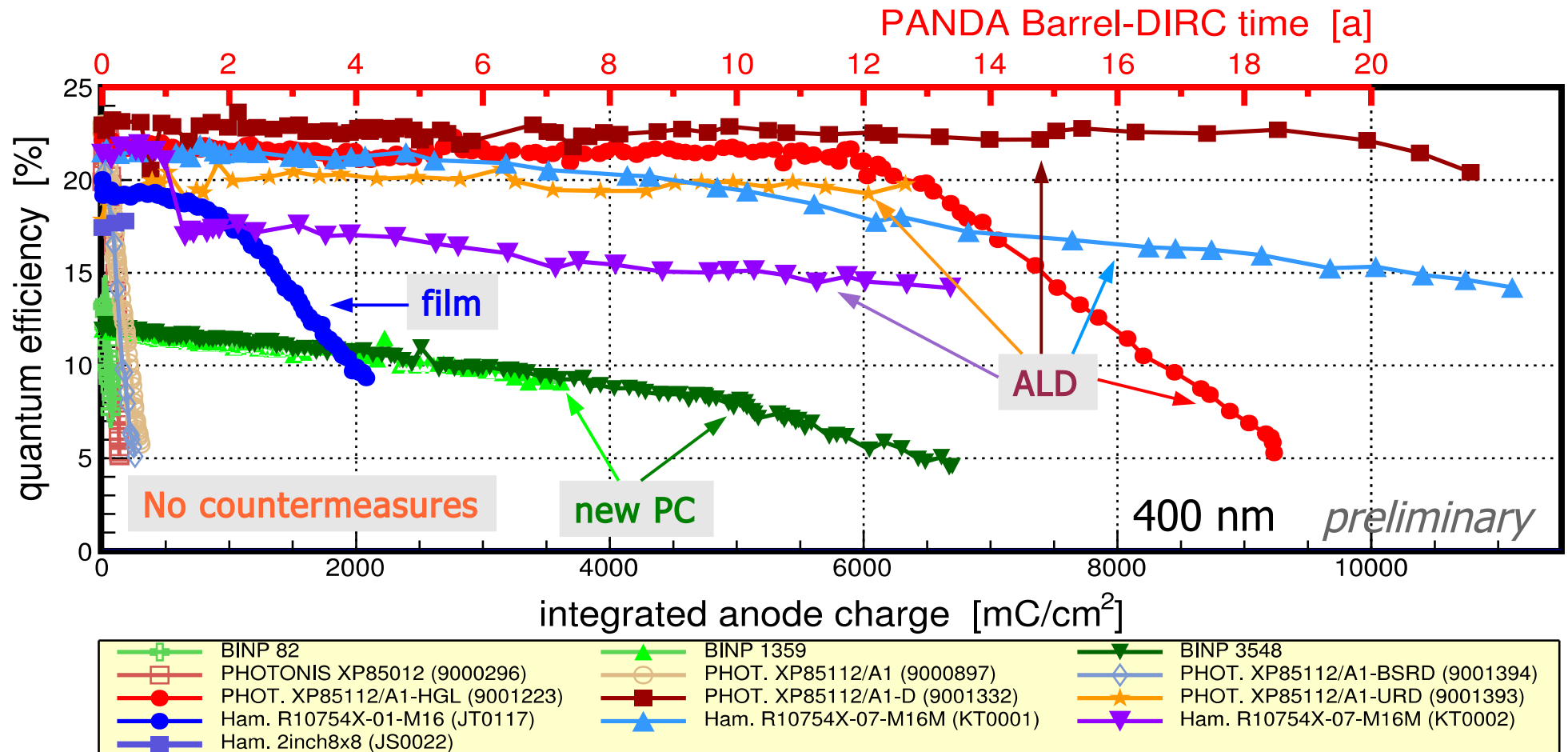
**PHOTONIS**  
2 inch

Status at  
Feb. 1, 2016

**Hamamatsu**  
1 inch



# Lifetime of MCP-PMTs (Feb. 2016)



- Hamamatsu film MCP-PMT: Q.E. drops beyond 1  $\text{C}/\text{cm}^2$
- Photonis 9001332: no Q.E degrading observed up to 10  $\text{C}/\text{cm}^2$
- MCP-PMTs with ALD layers: **very good performance to  $>6 \text{ C}/\text{cm}^2$**



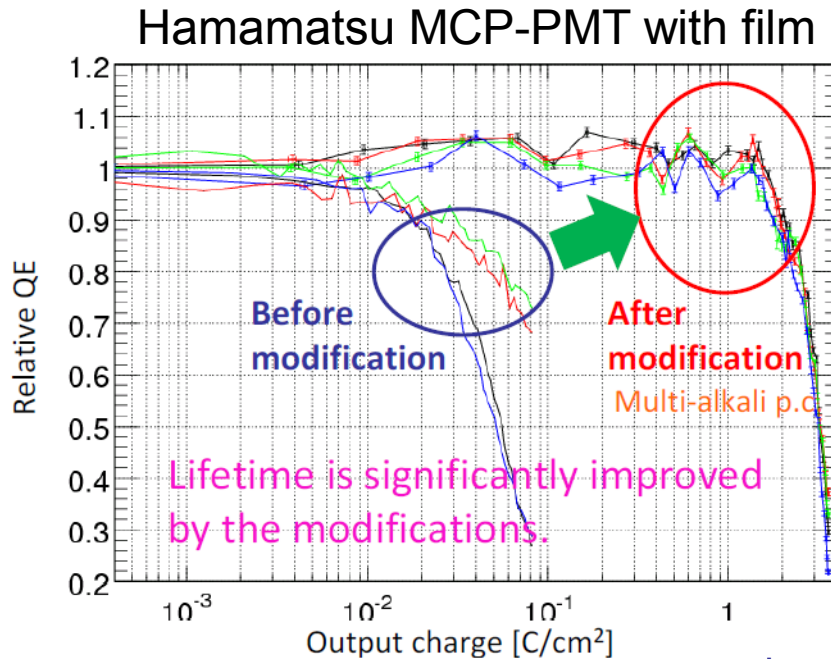
# Illumination Overview

	Sensor ID	Integral charge (Feb. 1, 2016) [mC/cm <sup>2</sup> ]	QE start [%]	QE latest [%]	QE latest / QE start [%]	Comments
Photonis XP85112	9001223	<b>9234</b>	22.11	5.29	<b>24%</b>	Start: 23 Aug. 11 Stop: 22 Sep. 15
	9001332	<b>10783</b>	22.62	20.42	<b>90%</b>	Start: 12 Dec. 12 ongoing
	9001393	<b>6329</b>	19.05	19.77	<b>104%</b>	Start: 23 Jan. 14 ongoing
Hamamatsu R10754X/R13266	JT0117 (M16)	<b>2086</b>	19.97	9.32	<b>47%</b>	Start: 23 Aug. 11 Stop: 24 Jul. 12
	KT0001 (M16M)	<b>11110</b>	21.71	14.21	<b>65%</b>	Start: 20 Aug. 13 ongoing
	KT0002 (M16M)	<b>6683</b>	21.14	14.18	<b>67%</b>	Start: 21 Oct. 13 ongoing
	JS0022 (2x2 inch <sup>2</sup> )	<b>189</b>	17.43	17.79	<b>102%</b>	Start: 11 Dec. 15 ongoing
BINP	1359	<b>3616</b>	12.27	9.06	<b>74%</b>	Start: 21 Oct. 11 Stop: 06 May 13
	3548	<b>6698</b>	12.23	4.58	<b>37%</b>	Start: 21 Oct. 11 Stop: 08 Jul. 15

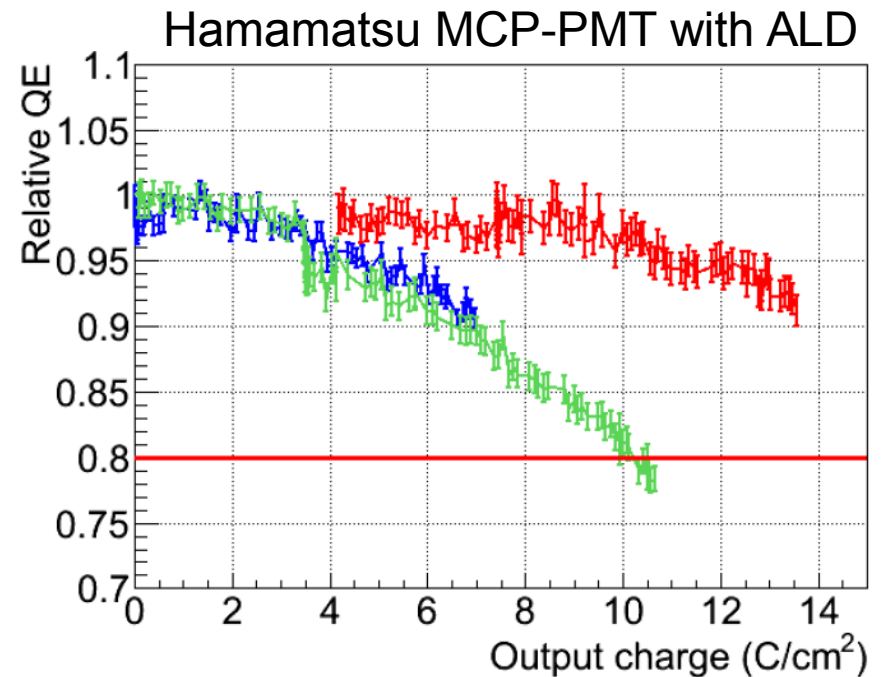


# Lifetime Results at Belle II

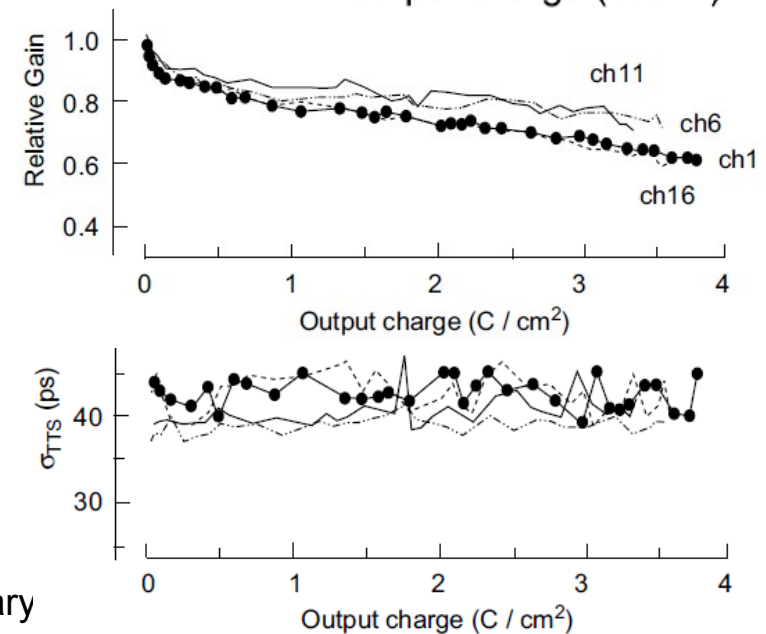
NIM A629 (2011) 111



K. Matsuoka, RICH2013



- Hamamatsu 1 inch MCP-PMTs with film good to  $\sim 2 \text{ C}/\text{cm}^2$
- Big improvement with ALD technique, but first results were not reproduced
- Moderate gain drop
- No changes in time resolution

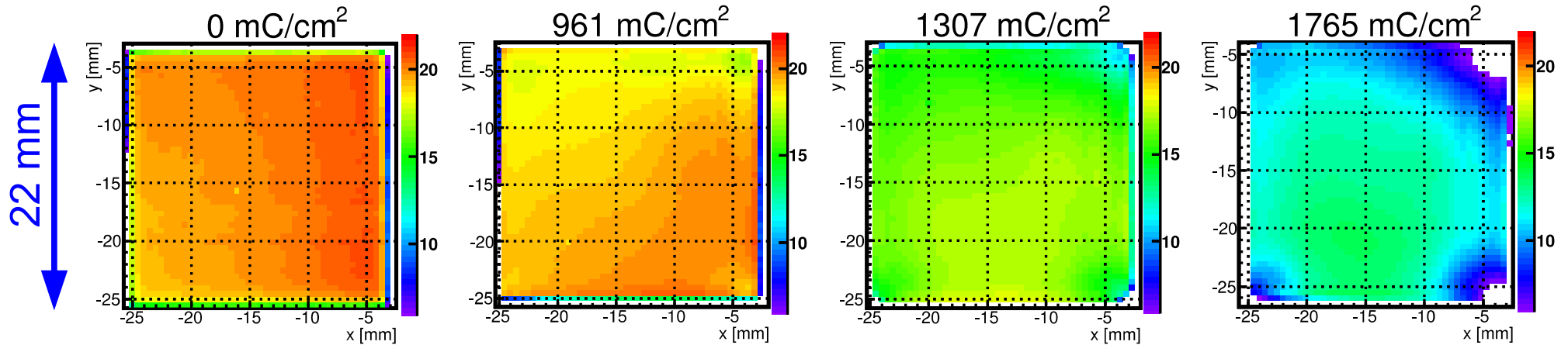


# Q.E. Scans (Hamamatsu & BINP)

Q.E. measured at 372 nm

film

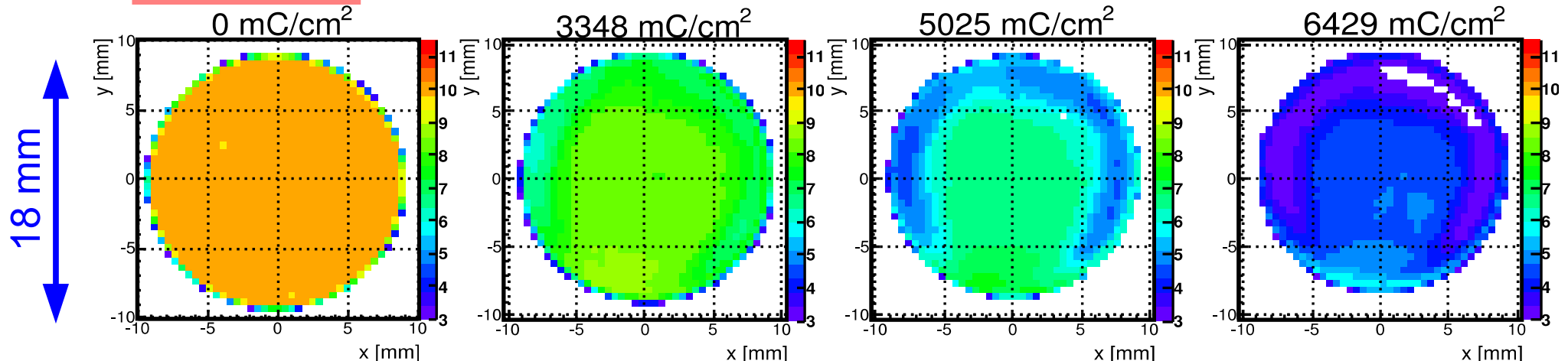
Hamamatsu R10754X-M16



new PC

BINP 3548

QE degradation evolves from rims and corners







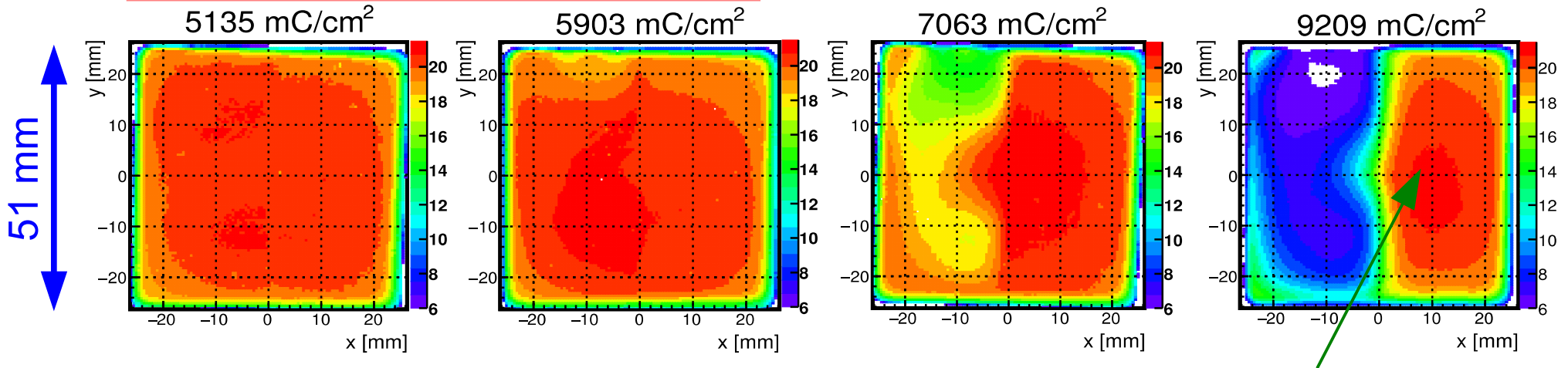
# Q.E. Scans (PHOTONIS ALD)

ALD

PHOTONIS XP85112 (9001223)

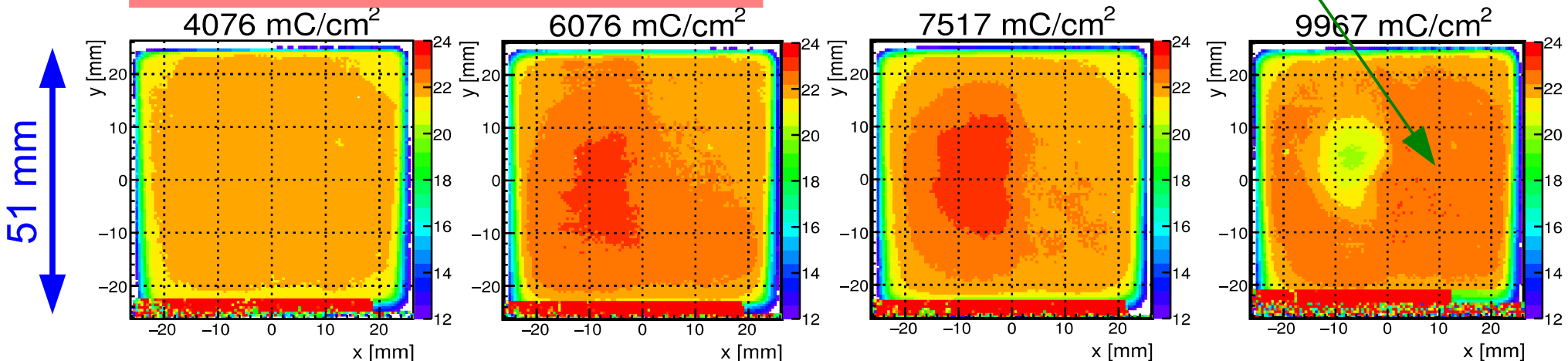
Q.E. measured at 372 nm

status December 2015



ALD

PHOTONIS XP85112 (9001332)





# Outlook

- Investigations to better understand the aging process
  - PHOTONIS XP85112 (9001223) is a unique MCP-PMT with an aged and an unaged half of the photo cathode (PC)
    - Is currently with PHOTONIS for non-destructive investigations of the PC
    - Spectroscopic ellipsometry to study refraction and absorption of both halves
    - I-V measurements of photoemission to check for work function changes
  - Identify the mass of the feedback ions with afterpulsing spectra
    - Many peaks and bumps visible in TOF spectra
    - Compare different types of MCP-PMTs (e.g., 10  $\mu\text{m}$ , 25  $\mu\text{m}$ , ALD, non-ALD)
- Accelerate aging and lifetime measurements
  - Saturation effects: aging speed depends on photon rate and intensity
    - M.Yu. Barnyakov and A.V. Mironov, 2011 JINST 6 C12026
  - Simultaneous current measurement at cathode and anode requires one potentialfree picoammeter



# Summary

- Aging symptoms
  - PC work function changes (darkcount, wavelength dependence)
  - PC damage usually starts from rims and corners
  - Ion feedback dominant reason for aging
- **Tremendous lifetime increase of latest MCP-PMTs** due to recent design improvements
  - application of ALD technique (x50 lifetime improvement)
  - huge step forward !
- Equipping the PANDA DIRCs and other high rate detectors with MCP-PMTs appears feasible